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FDME430NT N-Channel PowerTrench[®] MOSFET 30 V, 6 A, 40 m Ω

Features

- Max $r_{DS(on)}$ = 40 m Ω at V_{GS} = 4.5 V, I_D = 6 A
- Max $r_{DS(on)} = 51 \text{ m}\Omega$ at $V_{GS} = 2.5 \text{ V}$, $I_D = 5 \text{ A}$
- Max $r_{DS(on)} = 71 \text{ m}\Omega$ at $V_{GS} = 1.8 \text{ V}$, $I_D = 4 \text{ A}$
- Low profile: 0.55 mm maximum in the new package MicroFET 1.6x1.6 Thin
- Free from halogenated compounds and antimony oxides
- RoHS Compliant

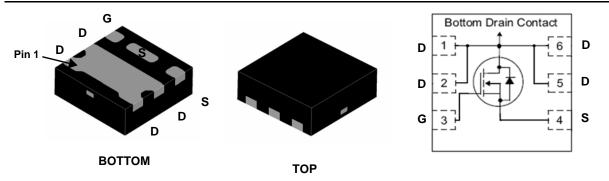


General Description

This single N-Channel MOSFET has been designed using Fairchild Semiconductor's advanced PowerTrench[®] process to optimize the $r_{DS(ON)}$ @ V_{GS} = 1.8 V on special MicroFET leadframe.

Applications

- Li-Ion Battery Pack
- Baseband Switch
- Load Switch
- DC-DC Conversion



MicroFET 1.6x1.6 Thin

MOSFET Maximum Ratings T_A = 25 °C unless otherwise noted

Symbol	Parameter			Ratings	Units	
V _{DS}	Drain to Source Voltage			30	V	
V _{GS}	Gate to Source Voltage			±12	V	
I _D	Drain Current -Continuous	T _A = 25 °C	(Note 1a)	6	•	
	-Pulsed			30	Α	
D	Power Dissipation for Single Operation	T _A = 25 °C	(Note 1a)	2.1	W	
P _D	Power Dissipation for Single Operation	T _A = 25 °C	(Note 1b)	0.7		
T _J , T _{STG}	Operating and Storage Junction Temperature Range			-55 to +150	°C	

Thermal Characteristics

R _{0JA}	Thermal Resistance, Junction to Ambient	(Note 1a)	60	°C/W	
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1b)	175	C/VV	

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
YA	FDME430NT	MicroFET 1.6x1.6 Thin	7 "	8 mm	5000 units

BV _{DSS}	Drain to Source Breakdown Voltage	$I_{D} = 250 \ \mu A, \ V_{GS} = 0 \ V$	30			V
$\frac{\Delta BV_{DSS}}{\Delta T_{J}}$	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu\text{A}$, referenced to 25 °C		22		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}$			1	μΑ
I _{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 12 V, V_{DS} = 0 V$			±100	nA
On Chara	acteristics					
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = 250 \ \mu A$	0.6	0.8	1.5	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 250 \ \mu\text{A}$, referenced to 25 °C		-3		mV/°C
		$V_{GS} = 4.5 \text{ V}, \ I_D = 6 \text{ A}$		25	40	
r	Drain to Source On Resistance	$V_{GS} = 2.5 \text{ V}, \ \text{I}_{D} = 5 \text{ A}$		29	51	mΩ
r _{DS(on)}		$V_{GS} = 1.8 \text{ V}, \ I_D = 4 \text{ A}$		38	71	
		$V_{GS} = 4.5 \text{ V}, I_D = 6 \text{ A}, T_J = 125 \text{ °C}$		34	54	1
9 _{FS}	Forward Transconductance	$V_{DS} = 5 V, I_{D} = 6 A$		31		S
Dynamic	Characteristics					
C _{iss}	Input Capacitance			572	760	pF
C _{oss}	Output Capacitance	─ V _{DS} = 15 V, V _{GS} = 0 V, f = 1 MHz		74	100	pF
C _{rss}	Reverse Transfer Capacitance			51	75	pF
Switchin	g Characteristics					
t _{d(on)}	Turn-On Delay Time			7	14	ns
t _r	Rise Time	$V_{DD} = 15 V, I_D = 6 A,$		3	10	ns
t _{d(off)}	Turn-Off Delay Time	$V_{GS} = 4.5 \text{ V}, \text{ R}_{GEN} = 6 \Omega$		19	34	ns
t _f	Fall Time			3.3	10	ns
Q _g	Total Gate Charge			6.5	9	nC
Q _{gs}	Gate to Source Gate Charge	$V_{DD} = 15 \text{ V}, I_D = 6 \text{ A},$ $V_{GS} = 4.5 \text{ V}$		0.9		nC
Q _{gd}	Gate to Drain "Miller" Charge	VGS - 7.0 V		1.6		nC
Drain-So	ource Diode Characteristics					
	Source to Drain Diode Forward Voltage	$V_{GS} = 0 V, I_S = 6 A$ (Note 2)		0.8	1.2	V
V _{SD}	Source to Drain Diode Porward Voltage	$V_{GS} = 0 V, I_S = 1.6 A$ (Note 2)		0.7	1.2	V
t _{rr}	Reverse Recovery Time	—I _F = 6 A, di/dt = 100 A/μs		12	22	ns
Q _{rr}	Reverse Recovery Charge	$F = 0 \Lambda$, $u/ut = 100 \Lambda/\mu$ s		2.9	10	nC
I. R _{0JA} is detern the user's box	nined with the device mounted on a 1 in ² pad 2 oz copper pa ard design. a. 60 °C/W when mounted a 1 in ² pad of 2 oz copp	on . 175	uaranteed by °C/W when n num pad of 2	nounted on a		ermined by
	ల దాది ది జి లంలంలం లంలంలం	ଦ ମ୍ମ ଅ ମ୍ମ ଅ ତ				
2. Pulse Test: P	Pulse Width < 300 μs, Duty cycle < 2.0%.					
2. Pulse Test: P						

Test Conditions

Min

Тур

Max

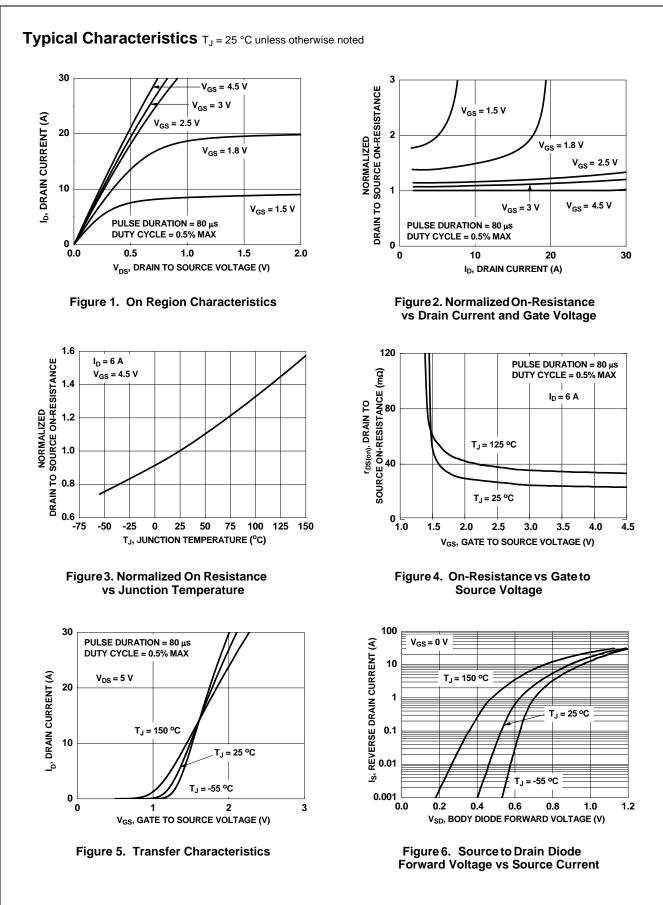
Electrical Characteristics $T_J = 25$ °C unless otherwise noted

Parameter

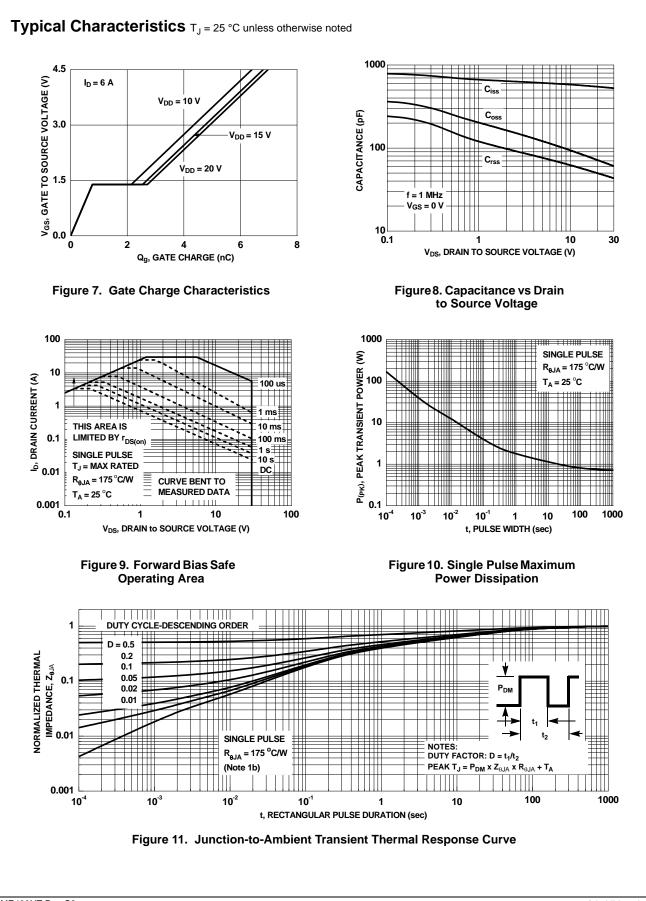
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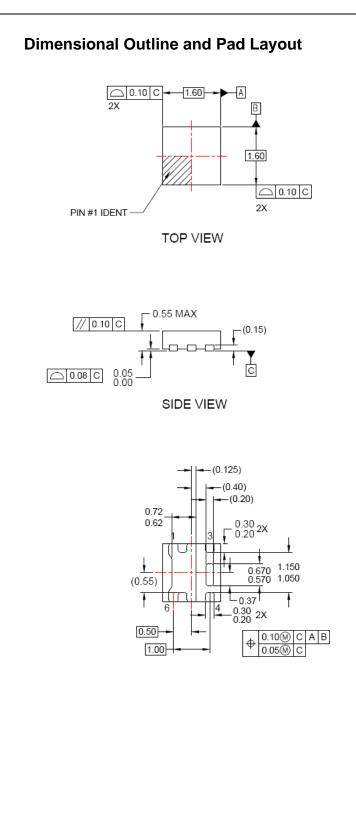
Off Characteristics

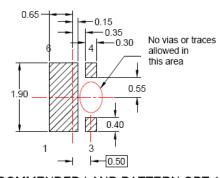
Units



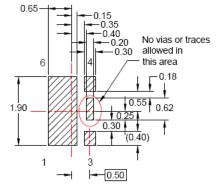








RECOMMENDED LAND PATTERN OPT 1



RECOMMENDED LAND PATTERN OPT 2

NOTES:

- A. DOES NOT FULLY CONFORM TO JEDEC REGISTRATION
- B. DIMENSIONS ARE IN MILLIMETERS.
- C. DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.
- D. LAND PATTERN RECOMMENDATION IS BASED ON FSC DESIGN ONLY

FDME430NT Rev.C3



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DME430NT N-Channel PowerTrench[®] MOSFE1

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